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## Energy dependent XPS measurements on thin films of a poly(vinyl methyl ether)/polystyrene blend concentration profile on a nanometer resolution to understand the behavior of nanofilms†

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The composition of the surface layer in dependence from the distance of the polymer/air interface in thin films with thicknesses below 100 nm of miscible polymer blends in a spatial region of a few nanometers is not investigated completely. Here, thin films of the blend poly(vinyl methyl ether) (PVME)/polystyrene (PS) with a composition of 25/75 wt% are investigated by Energy Resolved X-ray Photoelectron Spectroscopy (ER-XPS) at a synchrotron storage ring using excitation energies lower than 1 keV. By changing the energy of the photons the information depth is varied in the range from ca. 1 nm to 10 nm. Therefore, the PVME concentration could be estimated in dependence from the distance of the polymer/air interface for film thicknesses below 100 nm. Firstly, as expected for increasing information depth the PVME concentration decreases. Secondly, it was found that the PVME concentration at the surface has a complicated dependence on the film thickness. It increases with decreasing film thickness until 30 nm where a maximum is reached. For smaller film thicknesses the PVME concentration decreases. A simplified layer model is used to calculate the effective PVME concentration in the different spatial regions of the surface layer.

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## 1. Introduction

For decades, polymer blends have been an integral part of materials science due to their numerous applications. However, as the thermodynamics of blending polymers seldom allows polymers to be miscible, most polymer blends employed are immiscible. Nevertheless, thermodynamically miscible polymers could have multiple advantages for industrial applications. At the very least, miscible blends will be homogeneous at some spatial length scale, which could improve the final properties and the targeted quality.

Furthermore, the emergence of new advanced applications in functional coatings, batteries, innovative organic electronics, and hybrid materials depends strongly on organic and/or

polymeric materials, often blends, confined in thin films or at interfaces.<sup>1,2</sup> However, capturing the true potential of these materials requires a strong fundamental understanding upon which, tailor-made properties for the corresponding applications could be achieved. Consequently, research on blends of miscible polymers has received increased interest in recent years.<sup>3–11</sup> This includes studies on bulk miscible polymer blends, and polymer blends nanoconfined in thin films as well as thin films of polymer films with embedded nanoparticles.<sup>12</sup>

In general, blending of miscible polymers leads to a distribution of spatial compositions on the nanoscale, which are deviated from that of the bulk averaged concentration.<sup>13–15</sup> This not only influences properties like glassy dynamics,<sup>9–11,15,16</sup> glass transition and fragility (see for instance ref. 13, 15 and 17), but also wettability and adhesion<sup>18</sup> depending on the molecular weight used. This is also true for thin films. However, additional effects become more pronounced at the nanoscale. For instance, the surface tension of the components of the blend,<sup>19</sup> with respect to air and to the substrate, plays a key role. This is due to the surface enrichment and the preferential adsorption phenomena of one of the components relative to the other. This could further alter the compositional heterogeneities.

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Nevertheless, the latter phenomena and their effect on the overall molecular miscibility are still not well understood.

It has been known for some time that the thermal glass transition temperature  $T_g^{\text{therm}}$  of thin polymer films depends on the film thickness where an increase as well as a decrease of  $T_g^{\text{therm}}$ , compared to the bulk value, was observed depending on the polymer and the substrate.<sup>20–28</sup> A three-layer model has been introduced to discuss the thickness dependence of  $T_g^{\text{therm}}$  of thin polymer films.<sup>2</sup> It consists firstly of an adsorbed layer with a reduced segmental mobility, secondly a bulk-like layer in the middle of the film, and thirdly a surface layer with a higher molecular mobility. A more detailed discussion can be found in the ESI.† The measured thermal glass transition temperature of the whole film is a complicated average of all of these effects of the different layers.

Differently from the thickness dependence of  $T_g^{\text{therm}}$ , measured at the transition from an equilibrium melt to a nonequilibrium glassy state, the dynamic glass transition temperature  $T_g^{\text{dyn}}$  is measured in equilibrium at a given frequency, for instance by dielectric (BDS) or specific heat spectroscopy (SHS). Interestingly,  $T_g^{\text{dyn}}$  shows mostly no thickness dependence for the homopolymers studied.<sup>29,30</sup> In contrast, experiments on thin films of poly(vinyl methyl ether) (PVME)/polystyrene (PS) blends carried out by BDS and SHS showed a unique thickness dependence of  $T_g^{\text{dyn}}$ <sup>31–34</sup> while the  $T_g^{\text{dyn}}$  values for PS and PVME are independent of film thickness.<sup>28,35,36</sup> For instance, for the sample composition of 25 wt% PVME and 75 wt% PS, a complicated dependence of  $T_g^{\text{dyn}}$  on the film thickness has been found by SHS (see Fig. 1).<sup>30</sup>

$T_g^{\text{dyn}}$  increases with decreasing film thickness until a maximum at ca. 30 nm, where the value of  $T_g^{\text{dyn}}$  is approximately equal to that of PS, indicated by the dashed red line in Fig. 1. With a further decrease of the film thickness,  $T_g^{\text{dyn}}$  decreases. Madkour *et al.* hypothesized that this behavior is a counterbalance effect of a PVME-rich surface layer at the polymer/air interface and an adsorbed layer at the substrate.<sup>30</sup>

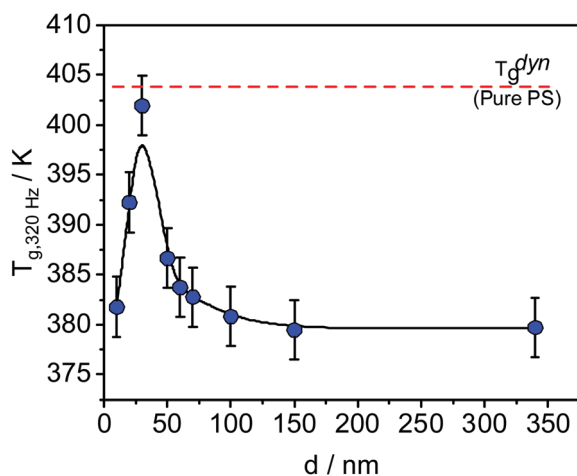


Fig. 1 Dynamic glass transition temperature as a function of the sample thickness measured with SHS at 320 Hz for thin films of the blend PVME/PS with the composition 25 wt%/75 wt%. The line is a guide for the eye. The data were taken from ref. 29.

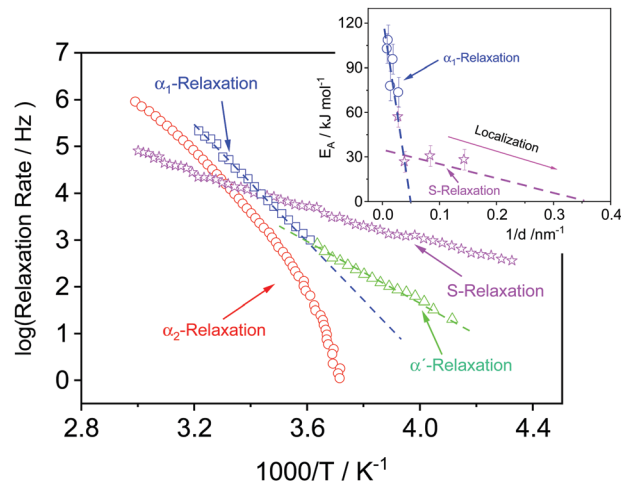


Fig. 2 Generalized relaxation map for thin PVME/PS films with the composition of 25 wt%/75 wt%: red –  $\alpha_2$ -relaxation for the 107 nm film measured by CEC, blue –  $\alpha_1$ -relaxation for the 107 nm film measured by CEC, green –  $\alpha'$ -relaxation for the 107 nm film measured by CEC. Please note that the  $\alpha'$ -relaxation is only observed for film thicknesses above 30 nm. Violet – S-relaxation for a 7 nm film measured by NSC. Lines are a guide for the eye. This process is observed only for thin films with film thickness of 30 nm and below. Inset: Activation energy versus inverse film thickness: blue –  $\alpha_1$ -relaxation, violet – S-relaxation. Lines are a guide for the eye. The data were taken from ref. 32.

Furthermore, for the exact same polymer blend, the molecular dynamics of the PVME within thin supported films was investigated by broadband dielectric spectroscopy (BDS) utilizing crossed electrode capacitors (CEC, film prepared between two Al electrodes) and also nanostructure capacitors (NSC, one free air/polymer interface).<sup>32</sup> It was shown that for bulk-like films (down to film thickness  $>110$  nm), three different relaxation processes were observed depending on film thickness denoted as  $\alpha_2$ ,  $\alpha_1$ - and  $\alpha'$ -relaxation. A generalized relaxation map showing the temperature dependence of the relaxation rates of all processes in Arrhenius coordinates is given in Fig. 2. The  $\alpha_2$ - and  $\alpha_1$ -relaxation are observed at temperatures above  $T_g^{\text{therm}}$ , whereas the  $\alpha'$ -process is found below  $T_g^{\text{therm}}$ . For thicker samples, the relaxation rates of the  $\alpha'$ -relaxation agree with that of the bulk, whereas for the thinner samples ( $<107$  nm) the process becomes too weak to be detected. The relaxation rates of the  $\alpha_1$ -relaxation were found to be thickness dependent, becoming faster compared to that of the bulk with decreasing film thickness. Furthermore, the apparent activation energy of this process decreases with decreasing film thickness (see inset Fig. 2). This result is explained by an increased localization of PVME segments compared with that of PS, resulting from different local compositions. In other words, even the bulk samples have three different local compositions resulting in a distribution of modes.

However, the dielectric spectra of supported films, with thicknesses of 37, 26, 12 and 7 nm showed a slightly different behavior. For the 37 nm thick film, the  $\alpha_1$ -relaxation is the dominant process in the spectra. The relaxation rates of this



process are shifted to higher frequencies, compared to the  $\alpha_1$ -relaxation obtained for the 37 nm film capped between two aluminum electrodes. This speeding-up of the molecular mobility was discussed in terms of a PVME-rich layer at the polymer/air interface.

Moreover, for the thinnest films (*ca.* <30 nm) an additional relaxation process was detected, which is called process S. It was assigned to fluctuations or adsorption/desorption processes of PVME segments within the loosely bound part of the adsorbed layer, proving that an PVME enrichment also takes place at the polymer/substrate interface. The apparent activation energy of the S-process has a different thickness dependence than that of the  $\alpha_1$ -relaxation, providing further evidence that the molecular origins of the two processes are different (see inset Fig. 2). Despite the strong proof and direct probing of the relaxation process assigned to the different compositional modes, the fundamental understanding of why the S process appears specifically around 30 nm, is still a mystery.

Until now, the concentration of PVME in the surface layer and the resulting compositional gradient within the film were investigated in dependence on the film thickness only for thick films with thicknesses larger than 100 nm and in the bulk state.<sup>37,38</sup> This work is concentrated on film thicknesses below 100 nm. An understanding and elucidation of the compositional gradient in thin films with thickness below 100 nm is required to understand the results obtained by BDS and SHS discussed above.

To further quantify and understand the compositional heterogeneities appearing at the air/polymer interface, the surface composition of PVME/PS blends was investigated using X-ray Photoelectron Spectroscopy (XPS).<sup>39,40</sup> In the conventional approach, one photon energy (Al  $K_{\alpha}$  radiation with an energy of 1486.6 eV) is used. For the relevant C1s photoelectrons, the information depth is about 10 nm for this photon energy. In this near-surface region, conclusions about local heterogeneities are not possible to draw. Moreover, for thin films with thicknesses of about 10 nm, the photoelectrons will originate from the entire film. Therefore, the obtained results would not deliver a description of the free surface layer, but approximately that of the entire film.

Besides XPS, Static Secondary Ion Mass Spectroscopy (SSIMS) was previously employed to investigate the surface composition of PVME/PS blends at the polymer/air interface.<sup>41,42</sup> This method is extremely surface-sensitive with an information depth of about 1 nm, but the quantification is difficult. Moreover, for the PVME/PS blend system, in some investigations one component has to be deuterated which has some influence on the miscibility.<sup>32</sup> In addition, ellipsometry<sup>43,44</sup> and attenuated total reflectance Fourier transform infrared spectroscopy<sup>45</sup> were also utilized. The latter method has a sampling depth of 3  $\mu\text{m}$ , which is also not suitable for studying thin films. Finally, neutron reflectivity can be employed to investigate the surface of thin films.<sup>37,46</sup> The investigations require one component to be deuterated to establish the necessary contrast. It is known that the deuteration changes the miscibility and so the phase diagram.<sup>32</sup> Therefore,

the results obtained for a deuterated system might be not comparable to those of a non deuterated one.

In principle, angle-dependent (conventional) XPS could be used to estimate the composition of a surface layer of a sample.<sup>36,47</sup> In this work, an alternative approach is introduced to study the compositional heterogeneities in thin films of polymer blends as a function of their film thickness, where a range of different photon energies is considered. This approach leads to different information depth and consequently to detailed information about the compositional heterogeneities in the respective ranges without sample destruction. Energy resolved XPS measurements have some advantages over angle dependent XPS experiments. The latter require a very flat surface. Moreover, the angle must be adjusted quite accurately to obtain reliable quantitative results especially when a larger series of samples are compared. Also, energy resolved measurements are a bit more surface sensitive. For angle dependent measurements, with increasing angle the intensity decreases and herewith the signal/noise ratio. This approach employed here gives a first overview about the vertical composition of the near-surface region of thin films with thicknesses below 100 nm, and detailed calculations, and simulations of the gradient structure of the thin polymer films are beyond the scope of this study.

The PVME concentration near the polymer/air interface of thin films of PVME/PS blends, with a nominal composition of 25/75 wt%, was measured using energy resolved XPS. These measurements were compared to conventional XPS measurements with a photon energy of 1486.6 eV. By analysis of the C1s peak, the concentration of PVME can be estimated in dependence on the information depth by keeping in mind that PVME consists of C–O and C–H bonds, whereas PS has only C–H bonds. Further concentration ratios will be considered in future work.

## 2. Experimental

### Materials

Polymers were purchased from Aldrich Inc. The polymers were used as received from the producer which ensured high purity. PVME was obtained as an aqueous solution (50 wt%, molecular weight  $M_w = 91 \text{ kg mol}^{-1}$ , polydispersity PDI = 2.1). PS has a molecular weight of  $524 \text{ kg mol}^{-1}$  and a PDI of 1.04.  $T_g^{\text{therm}}$  for the bulk state were determined by DSC (10  $\text{K min}^{-1}$ , second heating run) to be 246 K, 376 K and 293 K for dried PVME, PS, and PVME/PS 25/75 wt%, respectively. For details regarding film preparation, see ref. 32 and the ESI.† The samples were annealed at  $T_{g,\text{bulk}} + 50 \text{ K}$  for 72 h in an oil-free vacuum to remove residual solvent and stresses induced by spin coating.<sup>48</sup> The thickness of the film and its topography was determined by atomic force microscopy. No sign of dewetting was observed.

### XPS

Conventional XPS measurements were performed using a Kratos AXIS Ultra DLD with monochromatic Al  $K_{\alpha}$  radiation with an energy of 1486.6 eV. The samples were placed on a stainless-steel sample holder and fixed with double adhesive



carbon tape. The angle between the detector and the sample surface was 90 degrees (normal emission), and the angle between the X-ray source and the sample was 60 degrees. All spectra were processed using the program Unifit (version 2018). A sum of Lorentzian and Gaussian (L-G mixing of 0.2) was used as the fit function in combination with a Tougaard background. After fitting of the C1s spectra, all spectra were calibrated to the reference energy of the C1s component at 285.0 eV.

### BESSY

Energy resolved XPS measurements were carried out at the synchrotron BESSY II at Helmholtz Zentrum Berlin (HZB). The spectra were acquired at the HE-SGM monochromator dipole magnet CRG beamline at the photon energies given in Table S1 (ESI<sup>†</sup>) and Fig. 3. Like for the conventional measurements, the spectra were measured in normal emission. Here, the angle between the source and the sample was 45°. For the detection of the spectra a Scientia R3000 analyzer was used. All spectra were processed in the same way as the ones measured conventionally.

The effective attenuation lengths of the photoelectrons were determined using the NIST standard reference database (version 1.3, SRD 82).<sup>49</sup> For this estimation a band gap of 10 eV and a density for both polymers of 1.05 g cm<sup>-3</sup> was used. The uncertainty in the estimated mean free path length was 10%.<sup>50</sup>

## 3. Results and discussion

Fig. 4 illustrates, as expected, that two peaks occur in the measured C1s spectra, which are assigned to C-C (C-H) and C-O bonds. The weight fraction of PVME  $w_{\text{PVME}}$  is estimated from the areas under the peaks ( $I_{\text{C-H}}$  and  $I_{\text{C-O}}$ , see Fig. 4) using

$$\frac{I_{\text{C-O}}}{I_{\text{C-H}}} = \frac{2w_{\text{PVME}}/M_{\text{VME}}}{\frac{8(1-w_{\text{PVME}})}{M_{\text{S}}} + \frac{w_{\text{PVME}}}{M_{\text{VME}}}} \quad (1)$$

$M_{\text{VME}}$  and  $M_{\text{S}}$  are the molecular weights of the repeating units of PVME and PS, respectively. This procedure is repeated for each photon energy in dependence on the film thickness.

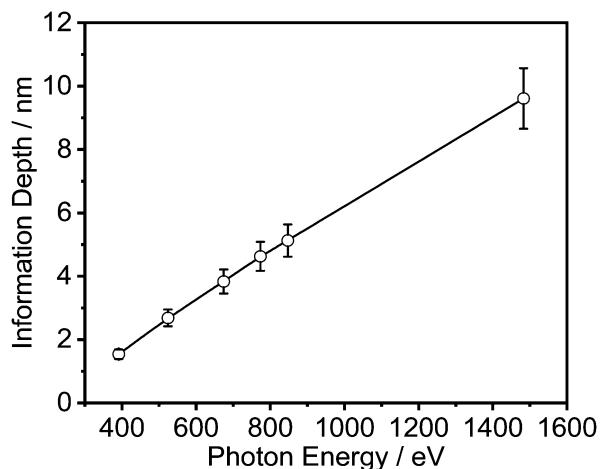


Fig. 3 Information depth vs. photon energy.

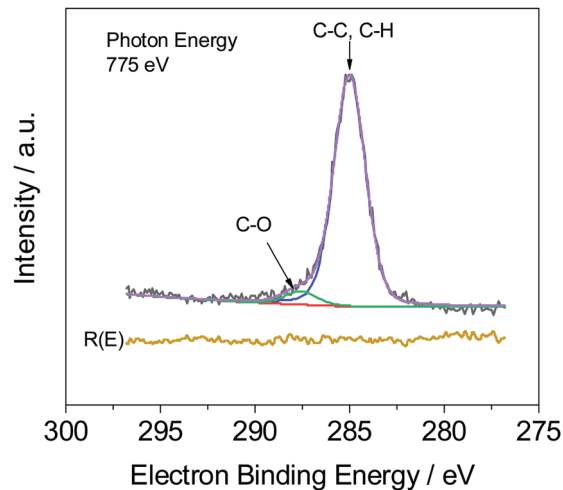


Fig. 4 C1s spectrum (black) for a 53 nm thick film. The green line corresponds to the contribution of the C-O bond and the blue line is the contribution of the C-H bond. The purple line is the whole fit and the red line depicts the background.  $R(E)$  (yellow line) is the residue of the fit.

The relative uncertainty of the whole procedure is estimated to be 20%.

However, the calculations are only correct for perfectly clean samples. In general, a thin layer of carbonaceous material is found on the surface of air-exposed materials (adventitious carbon). This adventitious carbon comprises hydrocarbon species with a small amount of oxygen functionalities,<sup>51</sup> which leads to additional contributions to the C-H peak. Such adventitious carbon is obtained on most air-exposed samples and has nothing to do with the employed polymers or its purity. Furthermore, a slight oxidation can be expected. The latter effect is considered in the uncertainty budget. The adventitious carbon is due to hydrocarbons adsorbed from the air atmosphere. However, due to the hydrocarbon contamination of the surface, the calculation of the weight fraction of PVME must be corrected. In particular, for the very surface-sensitive measurements with low excitation energies, a significant influence of this contamination layer can be expected. One possibility is to consider the surface contamination in the calculations of the effective attenuation length or in the simulations of the spectra of the films (see ref. 50 and references cited there). Here we have chosen an experimental approach and compared the composition of a pure PVME sample with a thickness of 15 nm which was kept in a vacuum, from preparation until the measurement at the theoretical  $I_{\text{C-O}}/I_{\text{C-H}}$  ratio of 2. (A C1s XPS spectrum of PVME is given in the ESI<sup>†</sup>, see Fig. S1.) By handling *in vacuo*, the surface contamination can be minimized. In this approach, a correction factor  $(1 + x)$  is introduced, which corrects the influence of the hydrocarbon contamination on the  $I_{\text{C-O}}/I_{\text{C-H}}$  ratio. This assumption of hydrocarbons as the main components in the surface contamination is well justified.<sup>51</sup> Following these considerations, a correction factor can be calculated according to

$$\frac{I_{\text{C-O}}}{I_{\text{C-H}}} = \frac{2}{1 + x} \quad (2)$$



Table 1 Correction factor  $1 + x$  for the different photon energies

$E/\text{eV}$	$1 + x$
392	11.9
525	7.21
677	5.18
775	3.85
848	4.24
1486.6	1.48

where  $x$  depends on the photon energy.  $1 + x$  is calculated from the ratios measured for the PVME sample. As expected,  $1 + x$  decreases with increasing photon energy and, herewith, with increasing information depth (see Table 1). This result shows that the correction is basically correct. Without correction unrealistic concentration values significantly higher than 100 wt% of PVME would be obtained. This correction procedure is applied to all data of the PVME/PS blend films. The influence of the correction is shown in Fig. 5 for a 45 nm thick film.

The obtained results are depicted in Fig. 6 and 7. For all film thicknesses and information depths, the concentration of PVME is increased compared to the bulk (formulated) concentration of 25 wt% (see Fig. 4). This result is already known from the literature. The surface enrichment of PVME at the polymer/air interface is due to the difference in the surface energies of the polymers with respect to air, which is  $\gamma_{\text{PVME}} = 36 \text{ mJ m}^{-2}$  for PVME and  $\gamma_{\text{PS}} = 40.2 \text{ mJ m}^{-2}$  for PS.<sup>38</sup> Therefore, the enrichment of PVME at the surface is energetically preferred. As is also known from the literature, the highest used X-ray energy of 1486.6 eV is not high enough to reach an information depth with the formulated concentration of PVME. In further work it is planned that hard X-rays will be employed to reach deeper regions. It must be noted that for all film thicknesses an enrichment of PVME in the near-surface region was observed, which conforms to the well-known findings from the literature.<sup>37,38</sup> Interestingly, the dependence of  $w_{\text{PVME}}$  at the information depth of 10 nm, which is typical for an XPS lab

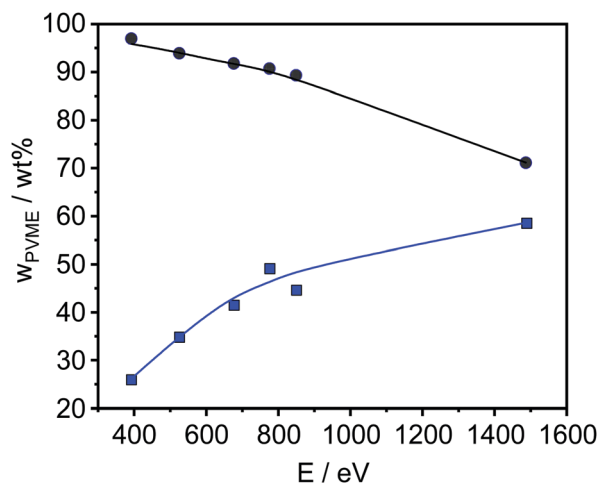


Fig. 5 PVME concentration versus photon energy of a 45 nm sample before (blue points) and after correction (black points). The lines are a guide for the eye.

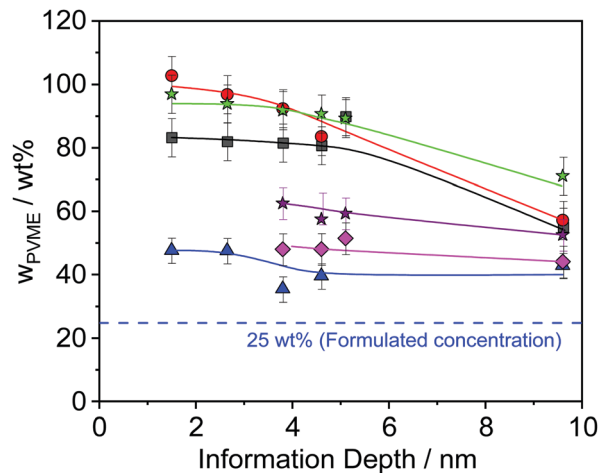


Fig. 6 PVME concentration vs. the information depth of the photons for different film thicknesses: black squares – 15 nm, red circles – 32 nm, green asterisk – 45 nm, violet asterisk – 62 nm, pink rhombus – 82 nm and blue triangle – 187 nm. The lines are a guide for the eye.

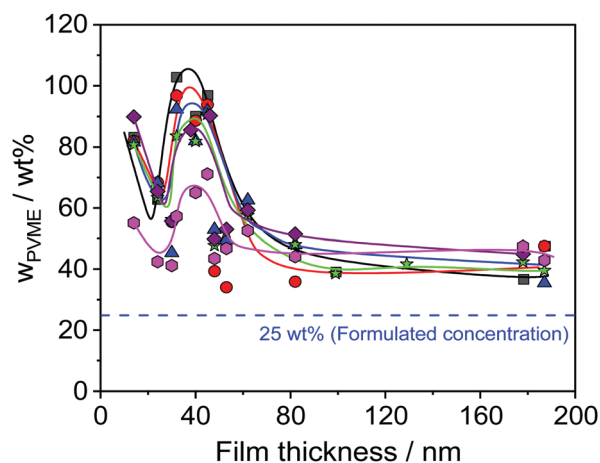


Fig. 7 PVME concentration versus thickness of the films for different photon energies. Black squares – 392 eV, red circles – 525 eV, blue triangles – 676 eV, green asterisks – 775 eV, violet rhombus – 849 eV, pink hexagons – 1486.6 eV. Lines are a guide for the eye.

experiment is less pronounced than for the lower information depths, which could only be investigated with the low excitation energies used at the synchrotron. This observation stressed the importance of such experiments for the structural elucidation of such films with thicknesses below 100 nm. It should be noted that the thinnest investigated film had a thickness of 15 nm. Therefore, the contributions from oxygen containing groups of the substrate should be quite small.

Theoretical approaches for the concentration profile based on a Flory–Huggins model predict an exponential decay.<sup>52</sup> These theoretical results were confirmed for a mixture of PVME blended with end-functionalized PS (symmetrical composition 50 wt%) with a film thickness larger than 100 nm.<sup>35</sup> A closer inspection of Fig. 6 reveals that the PVME concentration profile also decays exponentially for film thicknesses larger than



30 nm (see Fig. S2 in the ESI†) where the decay length depends on the film thickness. For a smaller film thickness the concentration does not decay exponentially. To discuss this in the framework of the theoretical approach given above one has to consider that this model consists of an air/polymer interface and an infinitely thick polymer film with no second interface. This means that this model cannot be appropriately applied for the thin films discussed here, especially for those with low film thickness where the influence of polymer/substrate interface also becomes more and more dominant. For a discussion of thin films, the model has to be extended by a second interface which is not in the scope of this work. Moreover, because no thickness of the polymer film is included in the mean field Flory–Huggins approach, the model cannot predict any thickness dependence.

Furthermore, Fig. 6 reveals that the concentration of PVME has a complicated dependence on the film thickness. Therefore, the concentration of PVME is plotted *versus* the film thickness in Fig. 7, for all photon energies.

Despite the scattering of the data (which reflects the measurement uncertainty within), Fig. 7 shows three features. Firstly, a minimum of  $w_{\text{PVME}}$  at 25 nm is observed. Secondly, a maximum between 30 nm and 40 nm is observed. For the maximum, the PVME concentration is about 100 wt% for the lowest photon energy. This means that a part of the surface layer with a thickness defined by the lowest photon energy consists only of PVME. The third feature is the saturation of  $w_{\text{PVME}}$  for film thicknesses higher than 50 nm. This means that for all photon energies, *i.e.* all information depths,  $w_{\text{PVME}}$  is about 40 wt% for film thicknesses above 50 nm. In other words, the composition of the film is relatively homogeneous in the outermost 10 nm. The almost constant level of the PVME concentration observed for film thicknesses higher than 50 nm is further called the saturation level.

The dependence of the PVME concentration on the film thickness observed in Fig. 7 shows a remarkable resemblance to the dependence of  $T_g^{\text{dyn}}$  on the film thickness depicted in Fig. 1. This is further supported by the fact that for films with a thickness of 30 nm,  $T_g^{\text{dyn}}$  is close to that of pure PS films as discussed in ref. 29 and 30. This could also be interpreted as a form of nanophase separation. To elucidate that, a simplified model is assumed. For the 30 nm film, the thickness of the near surface region close to the air/polymer can be estimated assuming an exponential decay of the outgoing photoelectrons, originating from the deeper parts of the film. Such an analysis will lead to a length scale where the number of photo electrons originating from PVME is decayed to  $1/e$ . The calculated PVME concentration in this near surface region decreases from 3.3 nm, for an excitation energy of 525 eV, to 2.7 nm for an excitation energy of 1486.6 eV, continuously. For sharp phase boundaries this value should be constant for all excitation energies. Therefore, this behavior can be explained as a near surface region of PVME with a slight intermixing between PVME and PS, resulting in a gradient of the PVME concentration. For film thicknesses smaller than 30 nm, the thickness of the bulk-like layer further decreases. Consequently, polystyrene

should be introduced into the surface layer, which leads to a lower amount of PVME in the outermost surface layer for all information depths (see Fig. 7). This also means that the PVME concentration in the bulk-like layer in the middle of the film increases. This result agrees with the decrease of  $T_g^{\text{dyn}}$  for film thicknesses smaller than 30 nm. This agreement provides further evidence that the correction for adventitious carbon is effective.

As discussed above for *ca.* 25 nm a local minimum is observed in the dependence of the PVME concentration on the film thickness (see Fig. 7). For film thicknesses smaller than 25 nm the PVME concentration increases again with a further decrease in film thickness. This increase in the PVME concentration might be assigned to the adsorbed layer. Therefore, hard X-ray photoelectron spectroscopy (HAXPES) investigations are necessary which are planned in the near future. Previously it was evidenced by solvent leaching experiments that the adsorbed layers in thin films of PVME/PS consist of PVME.<sup>31</sup> Nevertheless, differently from the adsorbed layer of leached films for the adsorbed layer within thin films it could not be excluded that some PS is also incorporated in the adsorbed layer especially for low film thicknesses. On the other hand, contributions from the topmost surface layer may also occur.

It is interesting to note that it was found by ellipsometry investigations that 30 nm is the film thickness where information from the adsorbed layer percolates to the bulk-like layer of the film.<sup>53</sup> Several further studies have also shown that at a threshold thickness of *ca.* 30 nm the thickness dependence of segmental dynamics and glass transition could change. This was shown for thin films of poly(2-vinyl pyridine) P2VP,<sup>54</sup> star-shaped PS,<sup>17</sup> and PVME/PS blends.<sup>29,31,32</sup> The reason behind this behavior is still not understood. For completeness it should be mentioned that there are also theoretical models for surface segregations including also further experimental data.<sup>55,56</sup>

Glor *et al.* showed for P2VP that with decreasing film thickness from 217 nm to 16 nm, the onset ( $T^+$ ) and offset ( $T^-$ ) temperatures of the glass transition shift to higher and lower temperatures, with respect to the bulk behavior, respectively. This behavior was discussed in terms of a gradient of the molecular mobility within the films. For thick films ( $\sim 217$  nm), the dynamics is homogeneous, and no influence of both interfaces could be observed. However, at 33 nm they proposed that the length scale of the gradient of the molecular mobility could reach at least 33 nm thus resulting in a sharp increase in the glass transition breadth. For thinner films than 16 nm two distinct transitions were observed, which were assigned both to two separate a glass transition related to both coexisting layers. This result might indicate that the gradient is not relevant anymore, where the difference in the molecular dynamics of the free surface and that of the irreversible adsorbed layer becomes too large to maintain a gradient in a 16 nm or thinner film. It should be noted that the temperature range measured in ref. 29 was broad enough to detect in principle the upper and the lower glass transitions. Nevertheless, only one glass transition was observed for the system discussed here.



Thin films of the PVME/PS blend could serve as a model system to shed some light on what happens to the molecular dynamics of the different layers within the thin films, utilizing the surface segregation phenomena, where differences in the molecular dynamics would be enhanced due to local compositional heterogeneities, induced by the asymmetry in the segmental dynamics of PVME and PS. To further understand the behavior seen at 30 nm film thickness, the gradient in the composition, which defines the compositional heterogeneities within the surface layer must be further quantified. In an attempt to do so, a very simplified approach is introduced. The calculation in this approach assumes that all photoelectrons from a depths does not exponential decay within the information depth. Therefore, this approach is semiquantitative and gives an idea about the compositional gradient within the different film thicknesses.

Here, the film down to an information depth of 9.6 nm from the air/polymer interface is approximated by sublayers having thicknesses corresponding to the different information depths of two neighboring photon energies  $Y_i = X_{i+n} - X_i$  where  $X_i$  and  $X_{i+n}$  are the information depths at a given photon energy  $i$  (see Fig. 8A). To avoid an overlap with the meaning of the layers discussed above these sublayers  $Y_i$  of the surface layer are further called information levels.  $n$  is the corresponding difference in the photon energies. The  $X_i$ ,  $Y_i$  and  $n$  values are given in Table 2. A local PVME concentration  $C_{loc}$  is considered for each information level, which can be iteratively estimated by

$$C_{loc} = \frac{w_{PVME}@X_{i+n} - C_{loc}@X_i \times SC}{(1 - SC)} \quad \text{for } n > 0 \quad (3)$$

where the signal contribution  $SC = Y_i/X_i$  is the contribution from the information level  $Y_i$  to the overall measured signal. This factor describes roughly how much of the signal is due to the information level above the considered information depth. An example of the calculation for the 45 nm film is given in Table 2.

Fig. 8A depicts a schematic representation of this concept. Fig. S3 in the ESI† gives an example of the local PVME concentrations for different information levels  $Y_i$  versus the film thicknesses. However, to compare the compositional gradient of different film thicknesses, the distance over which this gradient is taking place must be factored in. This is due to the fact that the miscibility of both compounds is not only due to the properties of the polymers but is also influenced by the presence of the interfaces. The relative influence of the interfaces on the miscibility will change with the film thickness. Therefore, the information depth point is normalized by the film thickness ( $X_i/\text{film thickness}$ ). The local PVME  $C_{loc}$  concentrations are plotted versus  $X_i/\text{film thickness} \times 100\%$  in Fig. 8B. The slope of this function represents the concentration gradient in the first 9.6 nm for each film thickness. The higher the slope, the stronger is the compositional gradient.

Fig. 8B reveals new insights into the compositional gradient and thus the dynamic heterogeneities of the surface layer as a function of the film thickness. First, as discussed above there is a kind of saturation level of the PVME concentration in the surface layer (minimum of surface enrichment of PVME), with

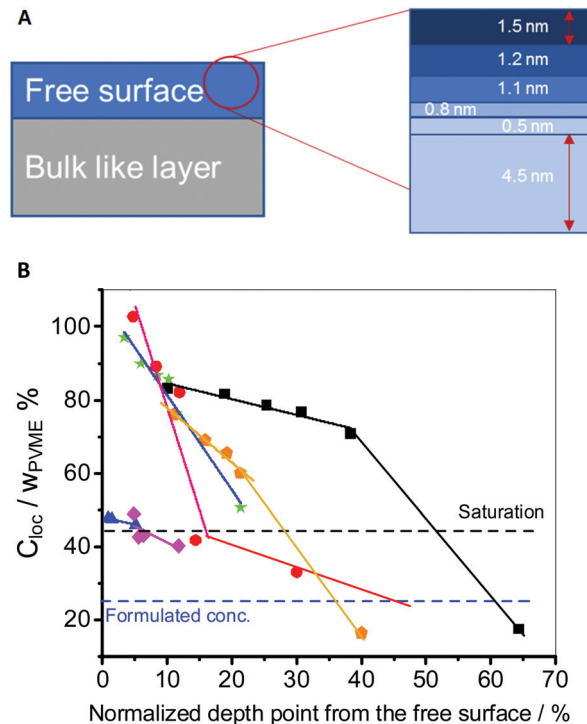


Fig. 8 (A) Schematic representation of the defined gradient measured and (B) local PVME concentration as a function of the information level ( $Y_i$ ) normalized by the film thickness for 187 nm – blue triangles, 82 nm – pink rhombus, 45 nm – green asterisks, 32 nm – red circles, 24 nm – yellow pentagons, and 15 nm – black squares. The dashed black line marks the saturation level whereas the dashed blue line marks the formulated concentration.

Table 2 Summary of the calculations for the 45 nm film

Photon energy ( $i$ )/eV	$n$ /eV	Information depth ( $X_i$ )/nm	Distance from the information level above ( $Y_i$ )/nm	SC	$C_{loc}/w_{PVME} \%$
392	0	1.5	1.5	1	97.0
525	133	2.7	1.2	0.44	90.1
676	151	3.8	1.1	0.29	86.6
775	99	4.6	0.8	0.17	85.6
849	74	5.1	0.5	0.10	76.3
1486.6	637.6	9.6	4.5	0.47	50.5

42 wt% PVME (observed for thick films: 200 nm to 80 nm). This probably means that at this level of confinement, the compositional heterogeneity gradient within the film is not too high and would reach the formulated concentration (25 wt% PVME) within the bulk-like layer. However, the low gradient translates to small incremental composition changes taking place over larger length scales. This results in a thick part of the surface layer with a different average compositional gradient as compared to the bulk like layer. The dynamics of both layers are heterogeneous, and no direct influence of either interface could be observed. Consequently,  $T_{g, \text{film}}^{\text{therm}} (> 100 \text{ nm}) = T_{g, \text{bulk}}^{\text{therm}}$  and  $T_{g, \text{film}}^{\text{dyn}} (> 100 \text{ nm}) = T_{g, \text{bulk}}^{\text{dyn}}$ .<sup>29</sup> This is also in line with the results obtained by BDS showing two cooperative segmental dynamic relaxations; the  $\alpha_1$ - and  $\alpha_2$ -relaxation similar to the bulk (see also Fig. 2).<sup>32</sup>



Due to mass conservation, a further decrease in the film thickness will take place at the cost of the thickness of the bulk-like layer. This results in a slight increase of  $T_{g, \text{film}}^{\text{dyn}}$  in the thickness range from 80 nm to 50 nm, as the effect of both PVME enriched interfaces influences the composition of the bulk-like layer, resulting in a higher PS concentration.

As discussed above, below 50 nm, the surface layer seems to form a nanophase separated layered structure. This takes place as the compositional gradient becomes higher within the film, due to the decrease of the thickness of the bulk-like layer over which the gradient could reach the saturation level and then the formulated concentration (Fig. 8B). At this length, the surface layer constitutes *ca.* 10–20% of the total film thickness, consisting of two sublayers: (I) an enriched PVME surface sublayer followed by (II) a PVME-rich sublayer (with a lower PVME concentration) starting from the saturation level concentration, which is higher than the formulated concentration. Additionally, the thickness of the adsorbed layer decreases slightly, as was recently shown in ref. 53, for identically prepared PVME films to the ones used here. This yields the observed increase in  $T_g^{\text{dyn}}$ , compared to the bulk value measured for thick films.

It is worth noting that it was shown in ref. 47 that thin films with thickness below 35 nm, could not form a stable leachable adsorbed layer. This was explained by the “loosely” bound part of the adsorbed layer starting to disappear, leaving only the strongly bound layer, which is susceptible to dewetting during the leaching experiments.

At *ca.* 30 nm, a threshold thickness is reached, where also due to mass conservation, the thickness of the adsorbed layer starts to decrease and so does its PVME concentration. This was confirmed by BDS,<sup>32</sup> where an additional localized relaxation process called “S-relaxation” was observed only for films with thicknesses of 30 nm and below (see Fig. 2). The activation energy of this process decreases with decreasing film thickness, pointing to further restriction of the PVME segments. This is probably due to higher PS concentration within the adsorbed layer, which induces the extra localization of the PVME segments (see inset Fig. 2).

Remarkably, the total thickness of the surface layer is not significantly changed, as depicted in Fig. 8B. Whereas the bulk-like layer is still constituting the largest portion of the film. This results in further compositional frustration, which results in a drastic increase in the PVME concentration of the outermost part of the surface layer.

This is also in agreement with BDS results for the exact same system.<sup>32</sup> In principle, the aforementioned PS-rich layer would have negligible signal in the dielectric spectra, due to the weak dipole moment of PS. This explains the observed disappearance of the  $\alpha_1$ -relaxation process for films with thicknesses below 26 nm.<sup>32</sup>

A further decrease in the film thickness (< 30 nm) underlines the discussed influences of both interfaces at the substrate and at the air/polymer interface. Consequently, the properties of the films are determined mainly by the surface and the interface. At this thickness, the formulated

concentration level (equilibrium level) could probably not be reached within a significant part of the film. This explains the yielded broadening in glass transition,<sup>30</sup> further decrease in  $T_g^{\text{dyn}}$ ,<sup>29</sup> (see Fig. 1), and the disappearance of  $\alpha_1$ -relaxation (only a more pronounced S-relaxation process).<sup>32</sup>

## 4. Conclusions

Here, energy resolved XPS measurements were presented for the thin films of the miscible blend PVME/PS with a composition of 25 wt%/75 wt%. This technique will provide information about the spatial distribution of PVME up to an attenuation length of *ca.* 10 nm depending on the photon energy. Firstly, it was found that the estimated concentration of PVME decreases with increasing photon energy. Secondly, the PVME concentration *versus* the film thickness shows a complex behavior. With decreasing film thickness  $w_{\text{PVME}}$  increases until a maximum at 30 nm where for the outermost nanometer *ca.* 100 wt% PVME was found. With a further decrease of the film thickness the concentration of PVME decreases indicating that the surface layer contains more polystyrene. At the lowest film thicknesses of 15 nm,  $w_{\text{PVME}}$  increases again which can be explained by the influence of the layer adsorbed on the substrate consisting mainly of PVME.

The data obtained here by energy resolved XPS agree with previous investigations on the same system by specific heat spectroscopy where a corresponding behavior was observed for the dynamic glass transition temperature. The results given here help to understand the thermal data better from a microscopic point of view.

## Author contributions

AS initiated and guided the project, MG prepared the samples and analyzed all the XPS measurements, and JR carried out the XPS measurements. SM and PS contributed significantly to the interpretation of the data. The manuscript was written by MG, SM and AS with contributions from JR and PS.

## Conflicts of interest

There are no conflicts to declare.

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